

# isc Silicon PNP Power Transistor

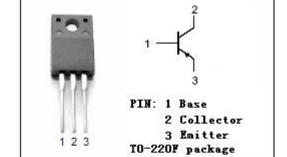
#### **DESCRIPTION**

- · Low Collector Saturation Voltage-
  - :  $V_{CE(sat)}$ = -1.7 $V(Max)@I_C$ = -3A
- Good Linearity of hFE
- Complement to Type KSD1408
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



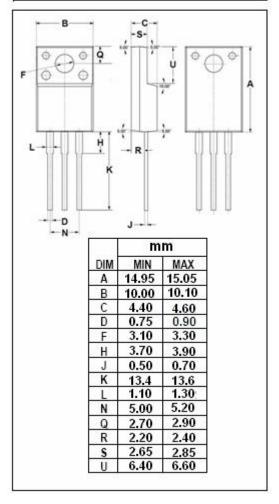
### **APPLICATIONS**

- · Designed for power amplifier applications.
- Recommended for 20~25W high-fidelity audio frequency amplifier output stage.



# ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>СВО</sub>	Collector-Base Voltage	-80	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-80	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V	
lc	Collector Current-Continuous	-4	А	
I <sub>B</sub>	Base Current-Continuous	-0.4	А	
P <sub>C</sub>	Collector Power Dissipation @ T <sub>a</sub> =25℃	2	W	
	Collector Power Dissipation @ T <sub>C</sub> =25°C	25		
TJ	Junction Temperature 150		°C	
T <sub>stg</sub>	Storage Temperature Range -55~150		$^{\circ}$	





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**KSB1017** 

#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -50mA; I <sub>B</sub> = 0	-80			V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -3A; I <sub>B</sub> = -0.3A			-1.7	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -3A; V <sub>CE</sub> = -5V			-1.5	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = -80V; I <sub>E</sub> = 0			-30	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-0.1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -0.5A; V <sub>CE</sub> = -5V	40		240	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -3A; V <sub>CE</sub> = -5V	15			
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = -10V; f= 1MHz		130		pF
f⊤	Current-Gain—Bandwidth Product	Ic= -0.5A; V <sub>CE</sub> = -5V		9		MHz

#### ♦ h<sub>FE-1</sub> Classifications

R	0	Y
40-80	70-140	120-240

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